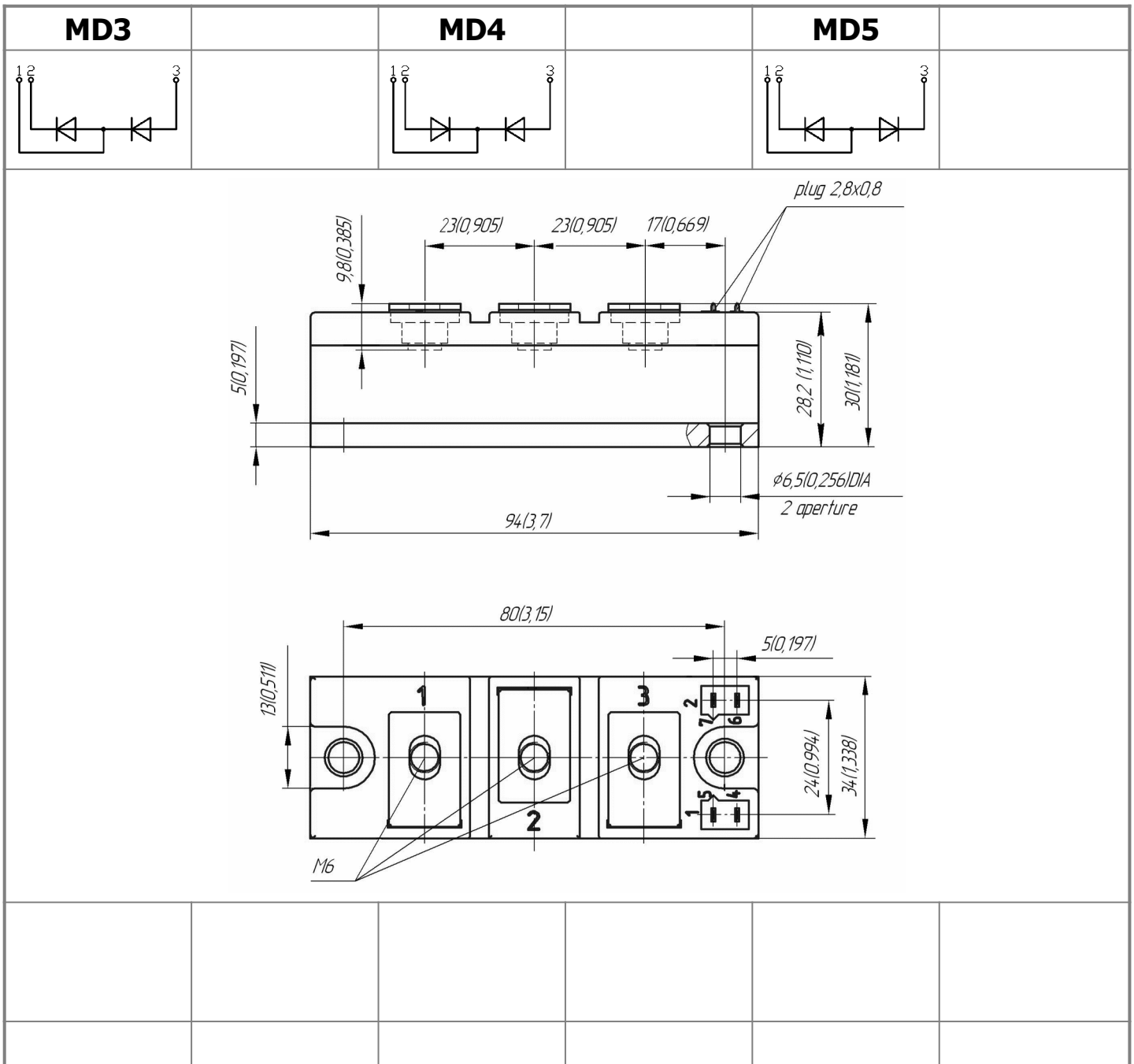




**Double Diode Module
For Phase Control
MDx-215-22-F**

Electrically isolated base plate
Industrial standard package
Simplified mechanical design, rapid assembly
Pressure contact

Average forward current	I_{FAV}	215 A
Repetitive peak reverse voltage	V_{RRM}	2000 ÷ 2200 V
V_{RRM}, V	2000	2200
Voltage code	20	22
$T_j, ^\circ C$	- 40 ÷ 150	



All dimensions in millimeters (inches)


MAXIMUM ALLOWABLE RATINGS

Symbols and parameters		Units	Values	Test conditions
ON-STATE				
I_{FAV}	Average forward current	A	215	$T_c = 100\text{ }^\circ\text{C}$;
I_{FRMS}	RMS forward current	A	337	180° half-sine wave; 50 Hz
I_{FSM}	Surge forward current	kA	6.4 7.5	$T_j = T_{j\max}$ $T_j = 25\text{ }^\circ\text{C}$ 180° half-sine wave; $t_p = 10\text{ ms}$; single pulse; $V_R = 0\text{ V}$;
			6.5 7.5	$T_j = T_{j\max}$ $T_j = 25\text{ }^\circ\text{C}$ 180° half-sine wave; $t_p = 8.3\text{ ms}$; single pulse; $V_R = 0\text{ V}$;
I^2t	Safety factor	$A^2s \cdot 10^3$	200 280	$T_j = T_{j\max}$ $T_j = 25\text{ }^\circ\text{C}$ 180° half-sine wave; $t_p = 10\text{ ms}$; single pulse; $V_R = 0\text{ V}$;
			170 230	$T_j = T_{j\max}$ $T_j = 25\text{ }^\circ\text{C}$ 180° half-sine wave; $t_p = 8.3\text{ ms}$; single pulse; $V_R = 0\text{ V}$;
BLOCKING				
V_{RRM}	Repetitive peak reverse voltages	V	2000÷2200	$T_{j\min} < T_j < T_{j\max}$; 180° half-sine wave; 50 Hz;
V_{RSM}	Non-repetitive peak reverse voltages	V	2100÷2300	$T_{j\min} < T_j < T_{j\max}$; 180° half-sine wave; single pulse;
V_R	Reverse continuous voltages	V	$0.6 \cdot V_{RRM}$	$T_j = T_{j\max}$;
THERMAL				
T_{stg}	Storage temperature	$^\circ\text{C}$	- 40 ÷ 50	
T_j	Operating junction temperature	$^\circ\text{C}$	- 40 ÷ 150	
$T_{c\text{ op}}$	Operating temperature	$^\circ\text{C}$	- 40 ÷ 125	
MECHANICAL				
a	Acceleration under vibration	m/s^2	50	

CHARACTERISTICS

Symbols and parameters		Units	Values	Conditions
ON-STATE				
V_{FM}	Peak forward voltage, max	V	1.40	$T_j = 25\text{ }^\circ\text{C}$; $I_{FM} = 500\text{ A}$
$V_{F(TO)}$	Forward threshold voltage, max	V	0.80	$T_j = T_{j\max}$;
r_T	Forward slope resistance, max	$\text{m}\Omega$	0.920	$0.5 \pi I_{FAV} < I_T < 1.5 \pi I_{FAV}$
BLOCKING				
I_{RRM}	Repetitive peak reverse current, max	mA	20	$T_j = T_{j\max}$; $V_R = V_{RRM}$
SWITCHING				
Q_{rr}	Total recovered charge, max	μC	810	$T_j = T_{j\max}$; $I_{FM} = 200\text{ A}$;
t_{rr}	Reverse recovery time, max	μs	17	$di_R/dt = -10\text{ A}/\mu\text{s}$;
I_{rrM}	Peak reverse recovery current, max	A	95	$V_R = 100\text{ V}$;
THERMAL				
R_{thjc}	Thermal resistance, junction to case			
	per module	$^\circ\text{C}/\text{W}$	0.0900	180° half-sine wave, 50 Hz
	per arm	$^\circ\text{C}/\text{W}$	0.1800	
	per module	$^\circ\text{C}/\text{W}$	0.0850	DC
per arm	$^\circ\text{C}/\text{W}$	0.1700		
R_{thch}	Thermal resistance, case to heatsink			
	per module	$^\circ\text{C}/\text{W}$	0.0300	
	per arm	$^\circ\text{C}/\text{W}$	0.0600	

INSULATION					
V _{ISOL}	Insulation test voltage	kV	3.00	Sine wave, 50 Hz; RMS	t=60 sec
			3.60		t=1 sec
MECHANICAL					
M ₁	Mounting torque (M6) ¹⁾	Nm	6.00	Tolerance ± 15%	
M ₂	Terminal connection torque (M6) ¹⁾	Nm	6.00	Tolerance ± 15%	
w	Weight, max	g	350		

PART NUMBERING GUIDE						NOTES					
MD	3	-	215	-	22	-	F	-	N		¹⁾ The screws must be lubricated
1	2		3		4		5		6		
1. MD - Rectifier Diode 2. Circuit Schematic 3. Average Forward Current, A 4. Voltage Code 5. Package Type (M.F) 6. Ambient Conditions: N – Normal											
		UL certified file-No. E255404									

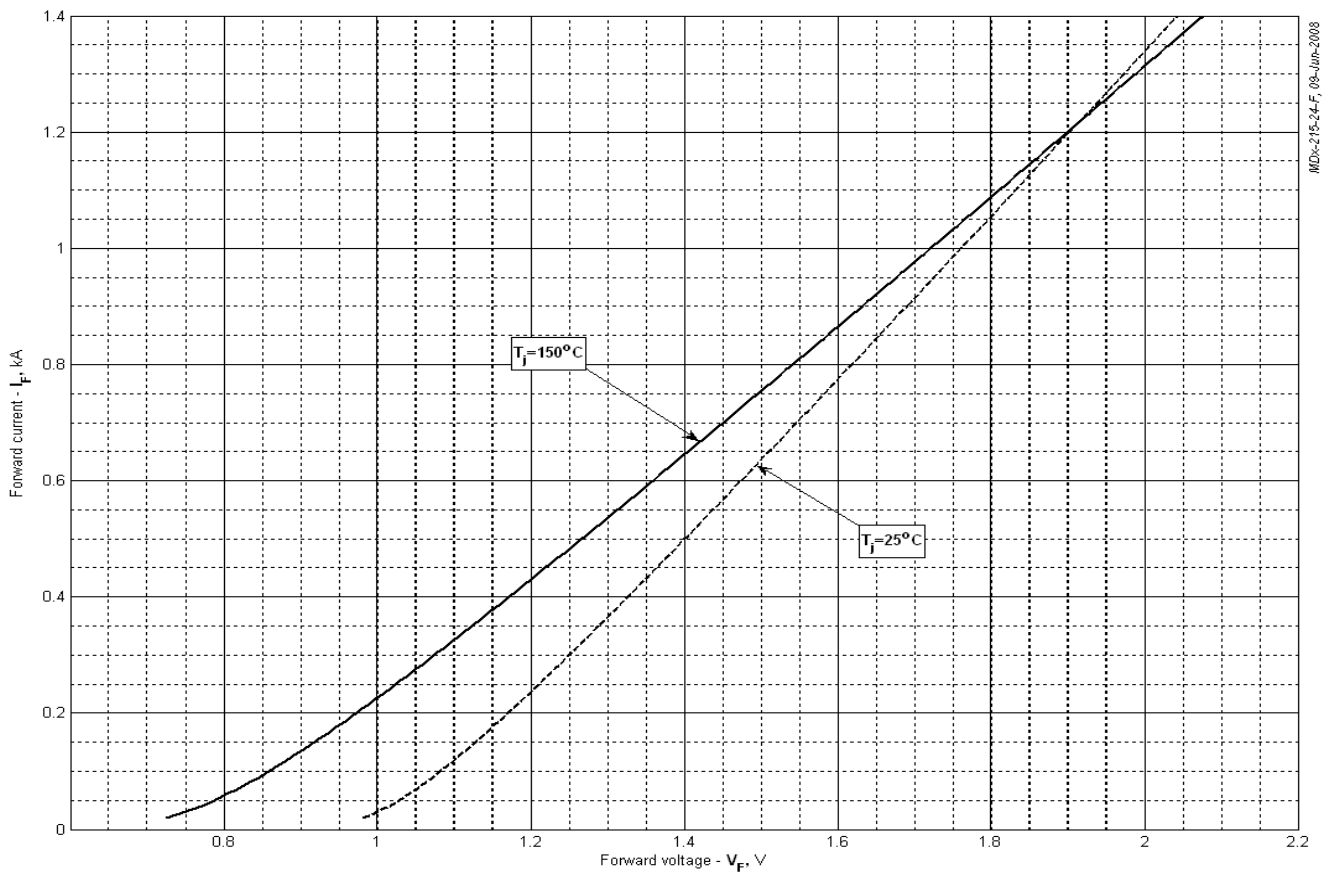


Fig 1 – On-state characteristics of Limit device

Analytical function for On-state characteristic:

$$V_F = A + B \cdot i_F + C \cdot \ln(i_F + 1) + D \cdot \sqrt{i_F}$$

	Coefficients for max curves	
	$T_j = 25^\circ\text{C}$	$T_j = T_{j\text{max}}$
A	0.928866	0.652364
B	0.673471	0.843733
C	-0.280459	-0.398101
D	0.352656	0.500582

On-state characteristic model (see Fig. 1)

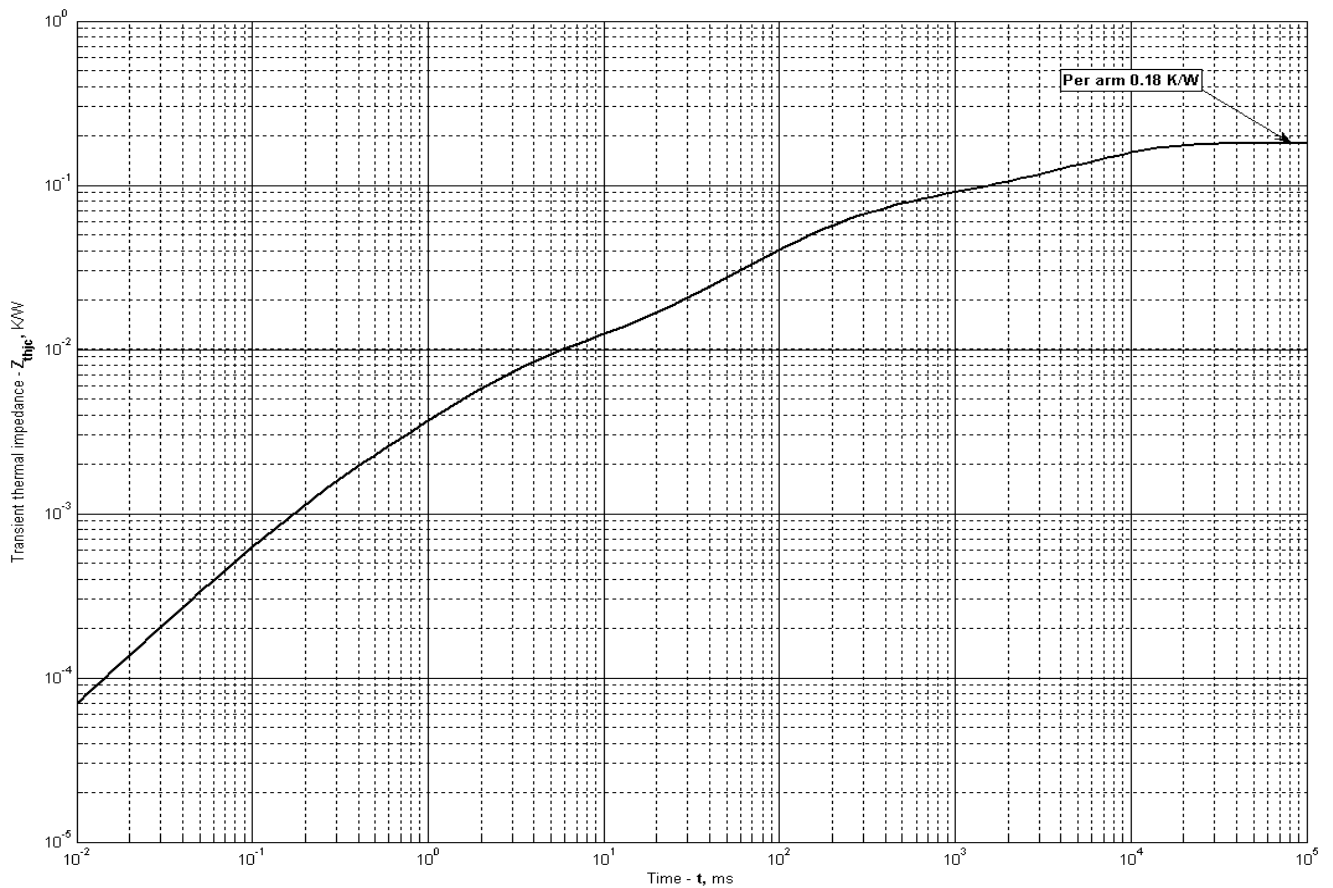


Fig 2 – Transient thermal impedance

Analytical function for Transient thermal impedance junction to case Z_{thjc} for DC:

$$Z_{thjc} = \sum_{i=1}^n R_i \left(1 - e^{-\frac{t}{\tau_i}} \right)$$

Where $i = 1$ to n , n is the number of terms in the series.

t = Duration of heating pulse in seconds.

Z_{thjc} = Thermal resistance at time t .

R_i = Amplitude of p_{th} term.

τ_i = Time constant of r_{th} term.

i	1	2	3	4	5	6
R_i, K/W	0.0007653	0.00703	0.01629	0.04126	0.01513	0.09951
τ_i, s	0.0002111	0.002366	0.06905	0.1909	0.6646	6.64

Transient thermal impedance junction to case Z_{thjc} model (see Fig. 2)

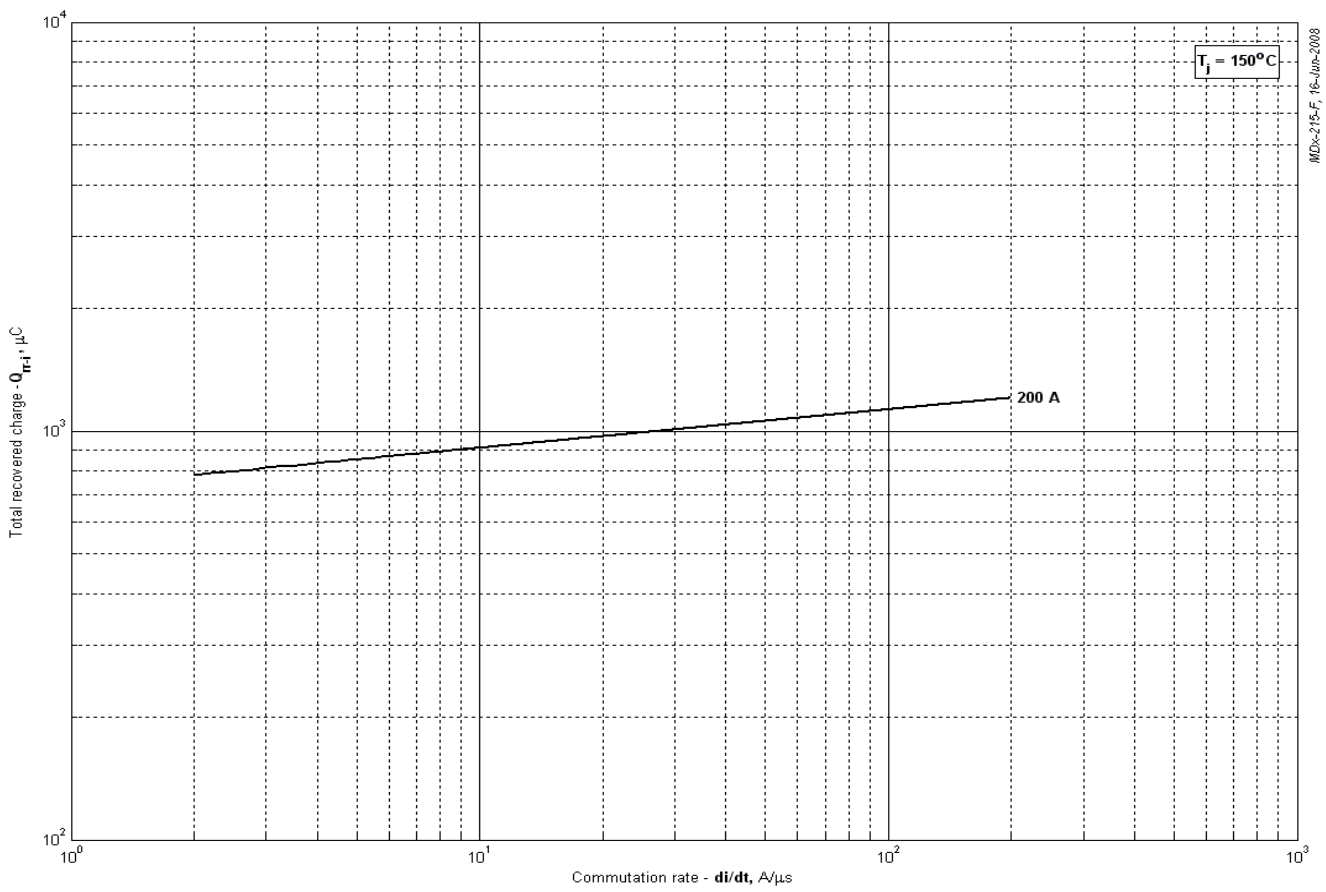


Fig 3 – Total recovered charge, Q_{rr-i} (integral)

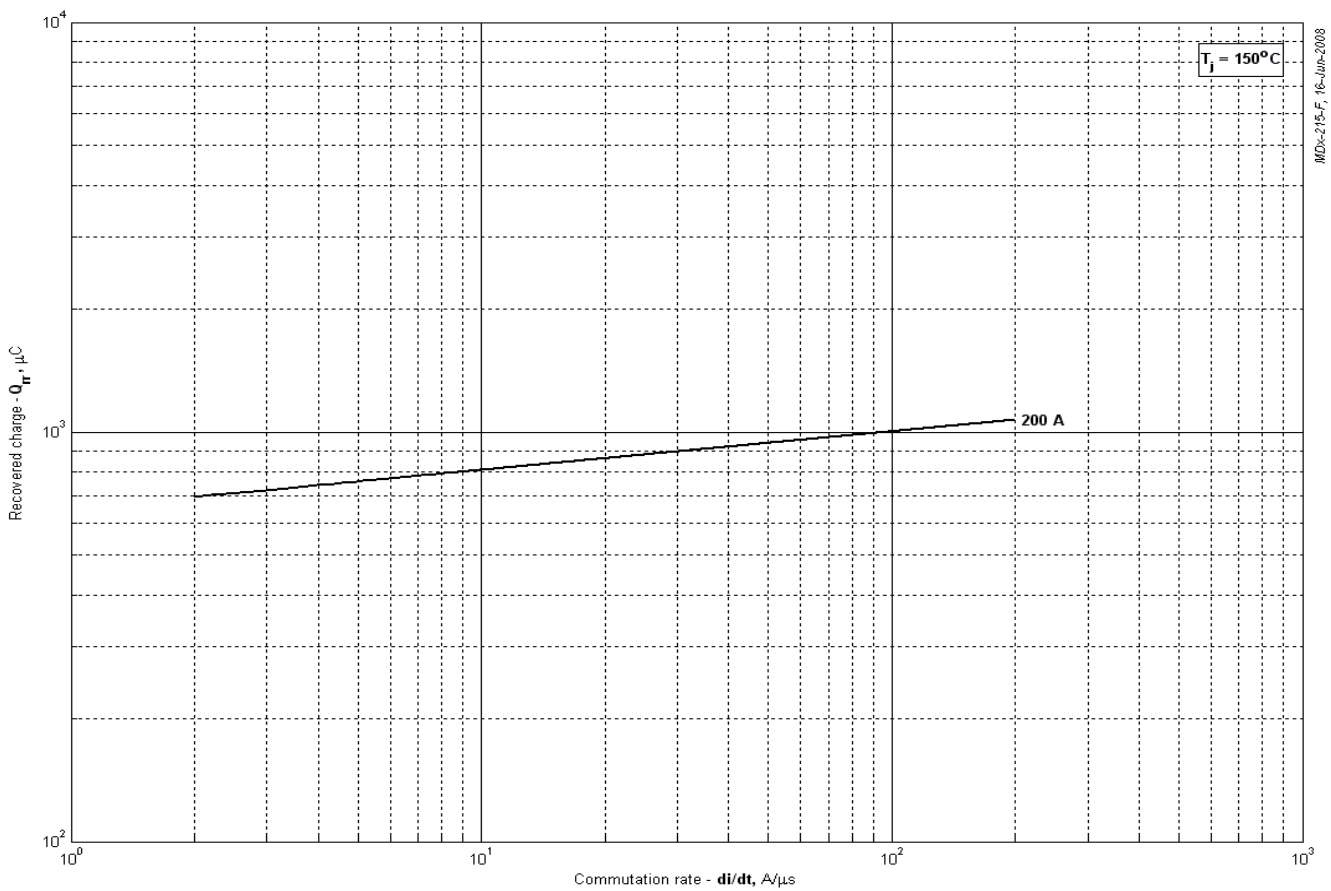


Fig 4 - Recovered charge, Q_{rr} (25% chord)

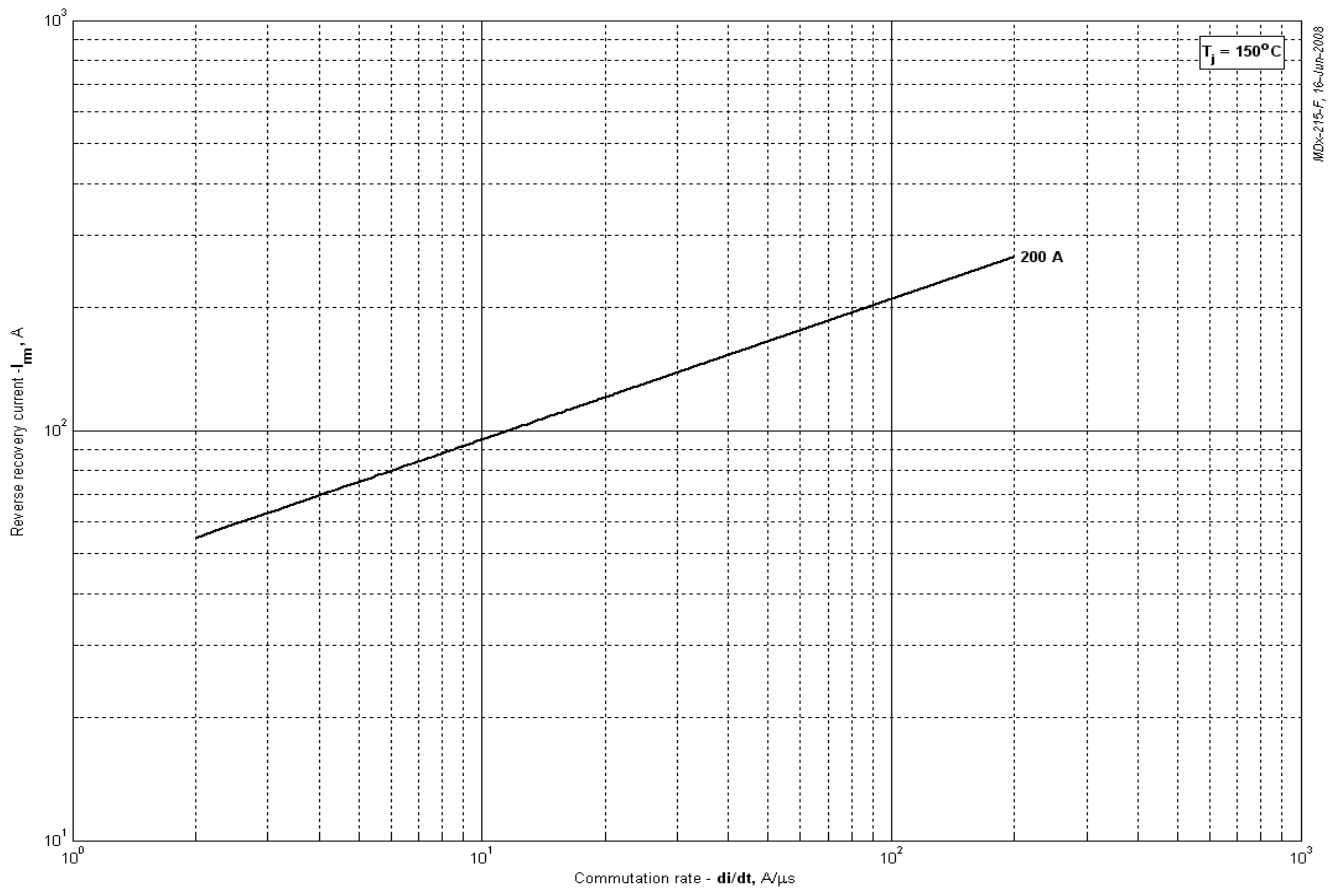


Fig 5 – Peak reverse recovery current, I_{rm}

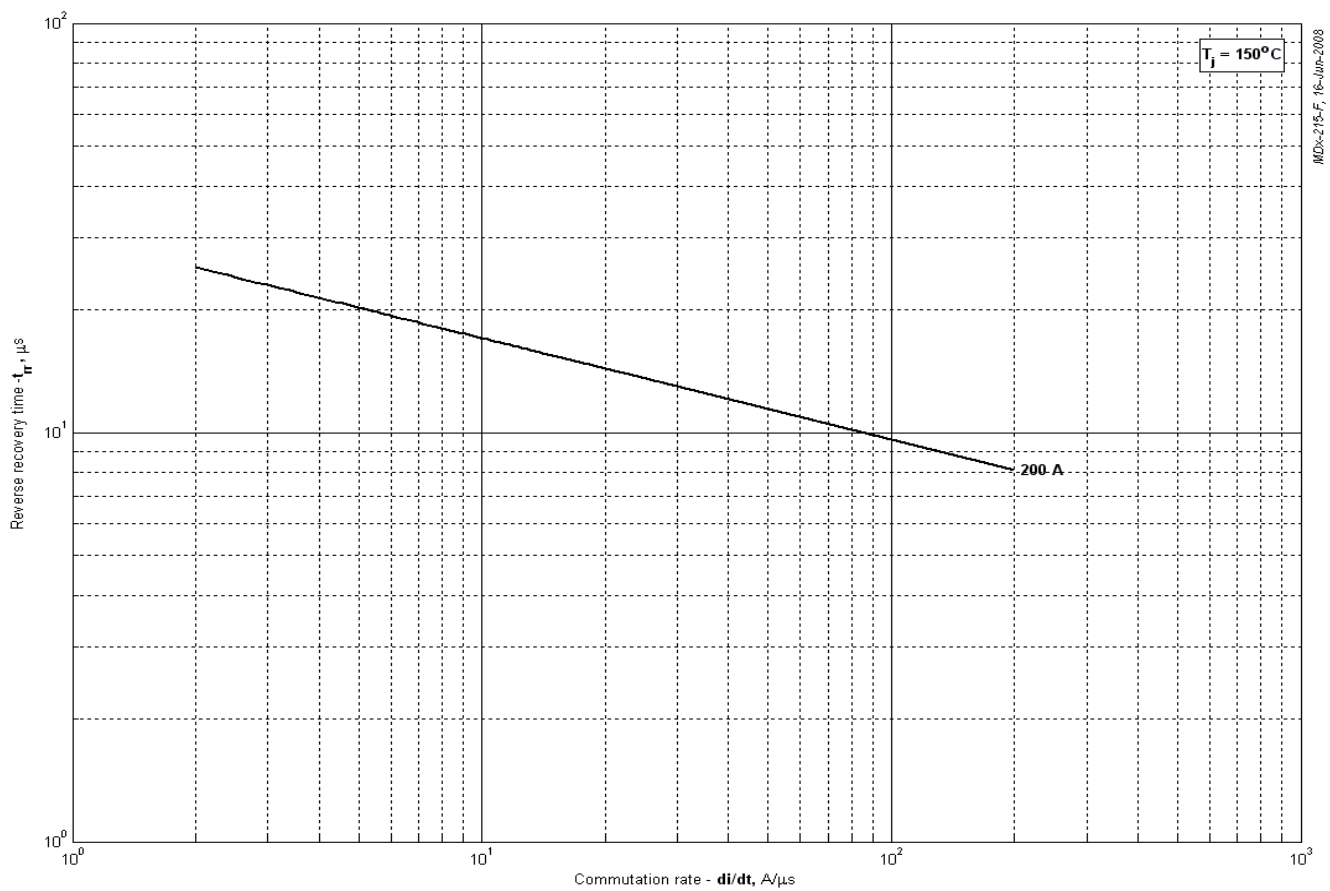
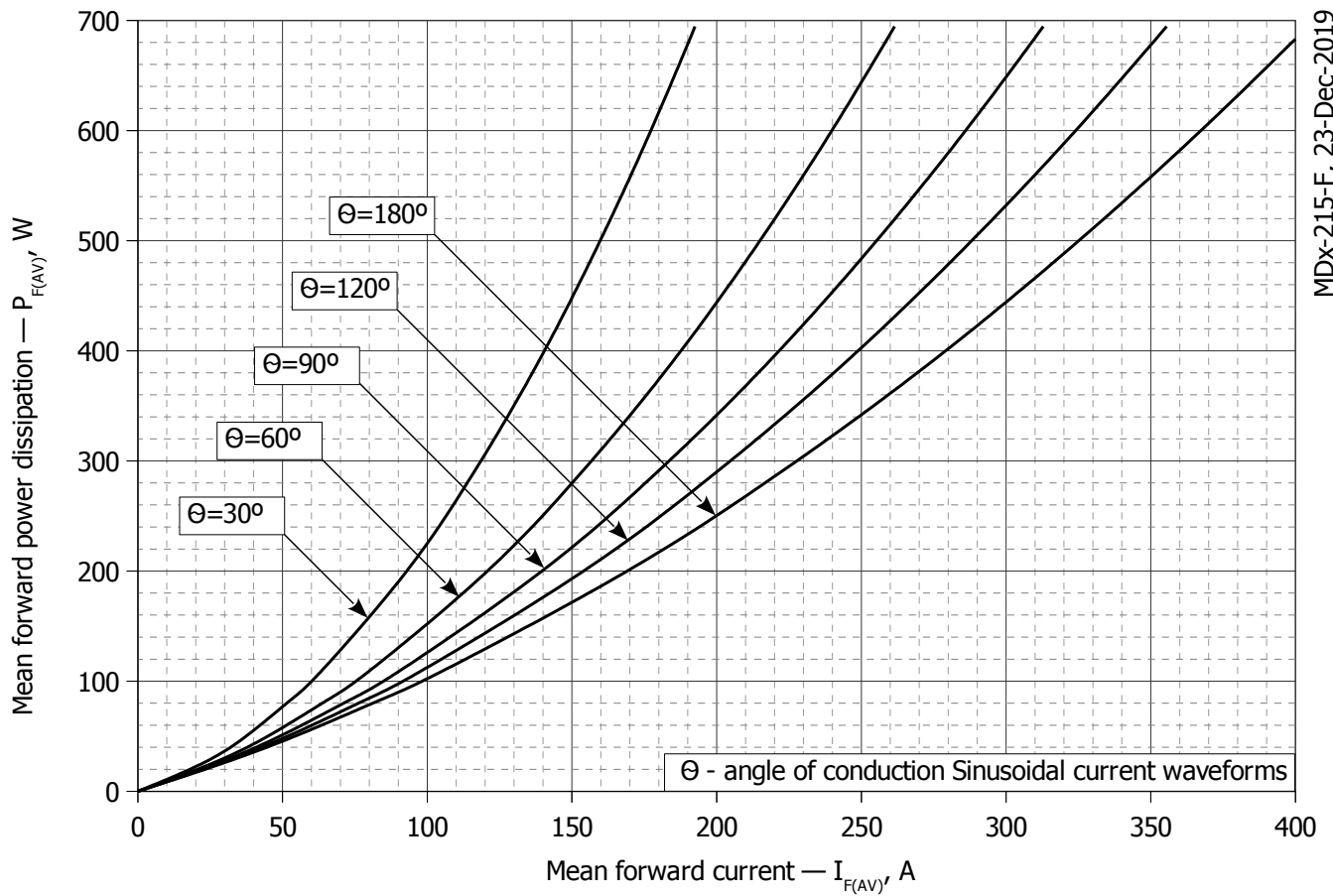
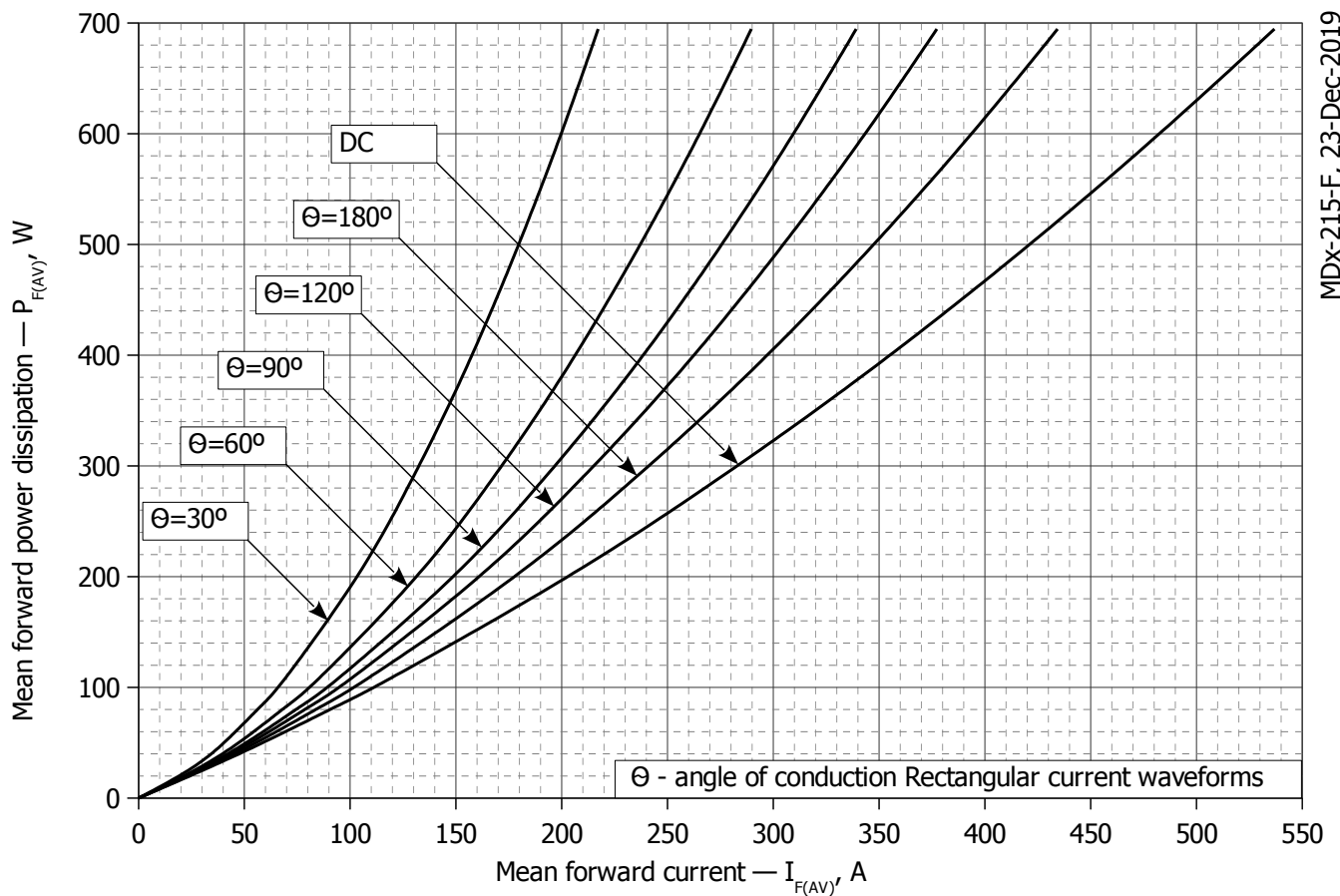


Fig 6 – Maximum recovery time, t_{rr} (25% chord)



MDX-215-F, 23-Dec-2019

Fig 7 – On-state power loss (sinusoidal current waveforms)



MDX-215-F, 23-Dec-2019

Fig 8 – On-state power loss (rectangular current waveforms)

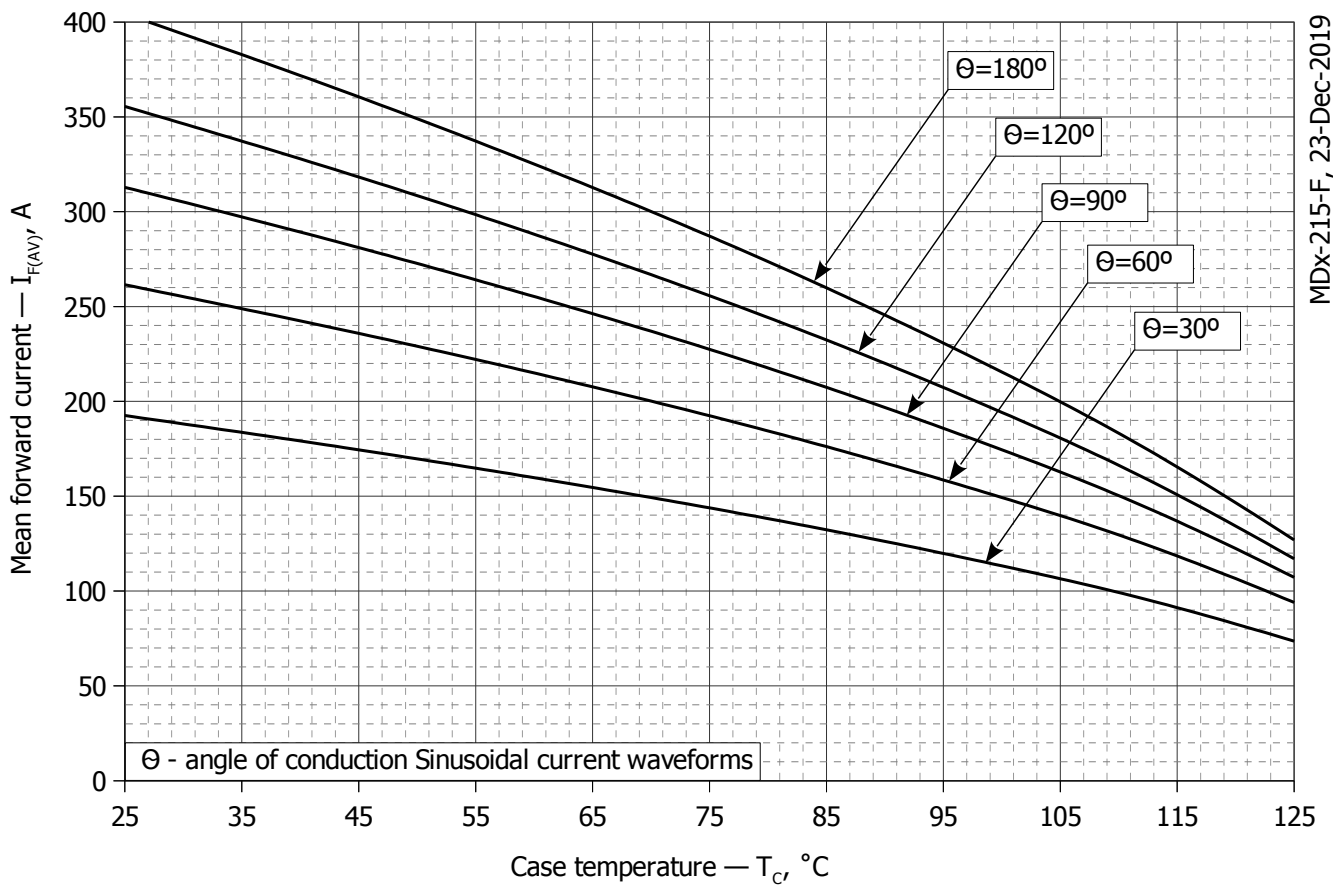


Fig 9 – Maximum case temperature DSC (sinusoidal current waveforms)

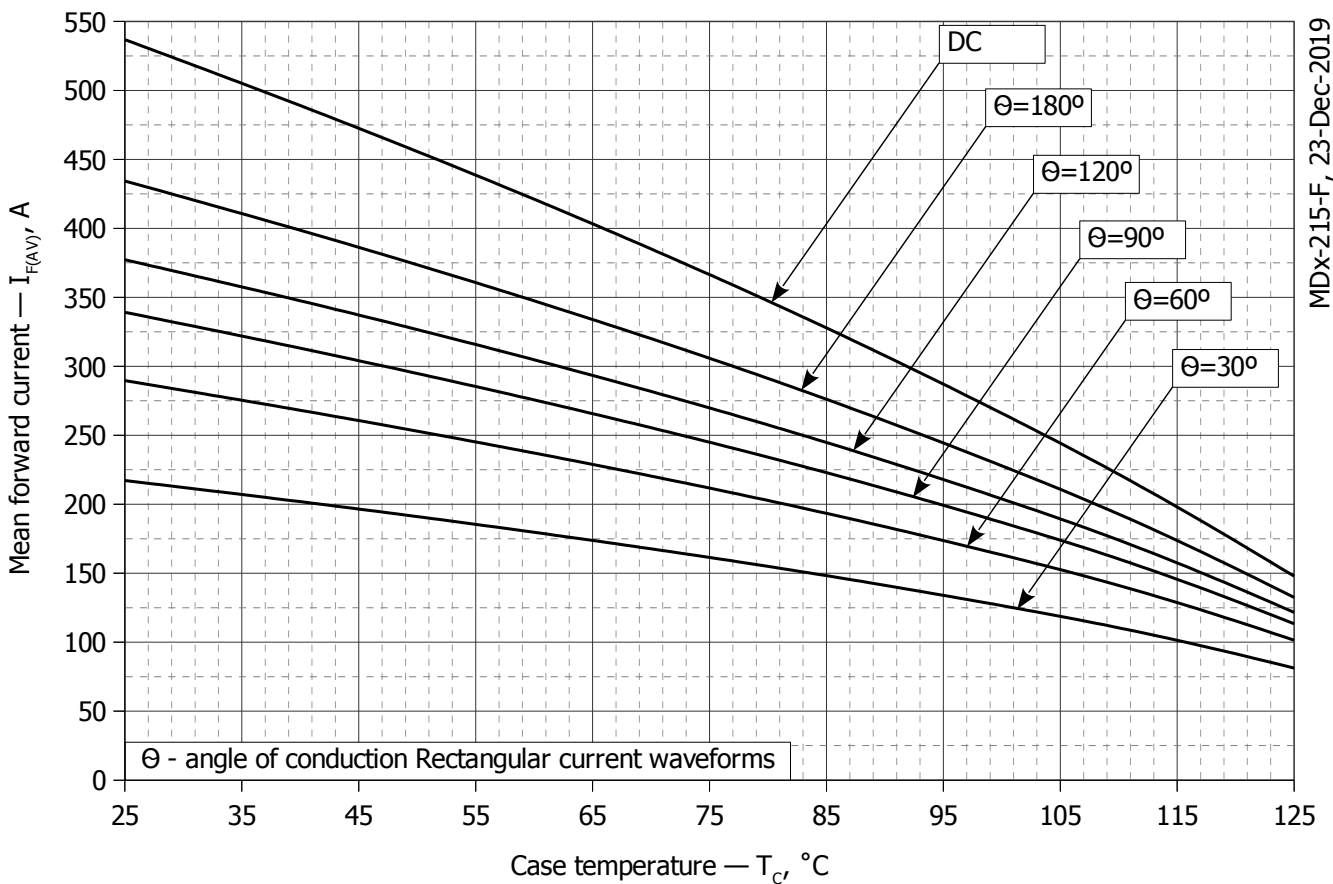


Fig 10 – Maximum case temperature DSC (rectangular current waveforms)

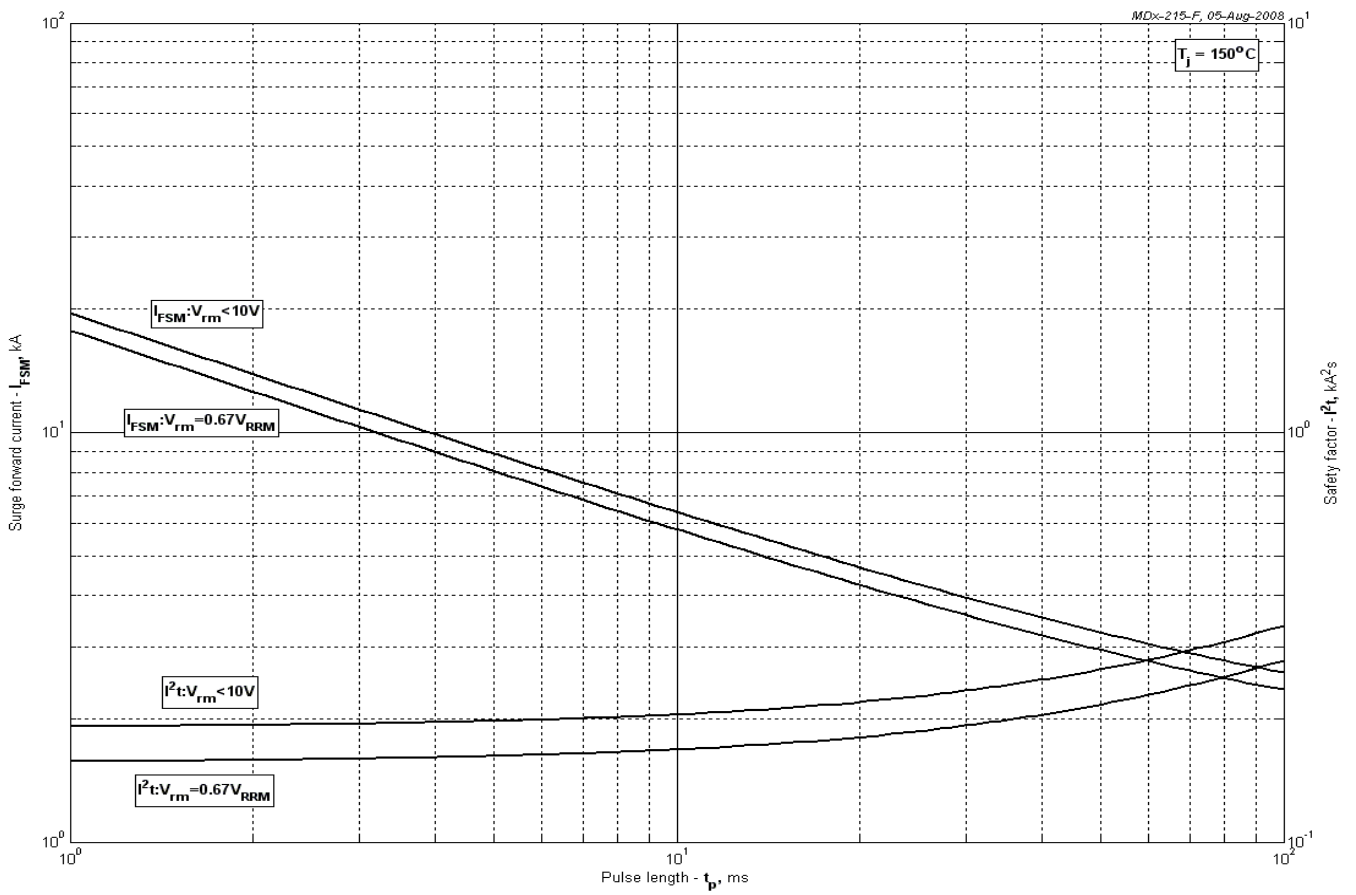


Fig 11 – Maximum surge and I^2t ratings

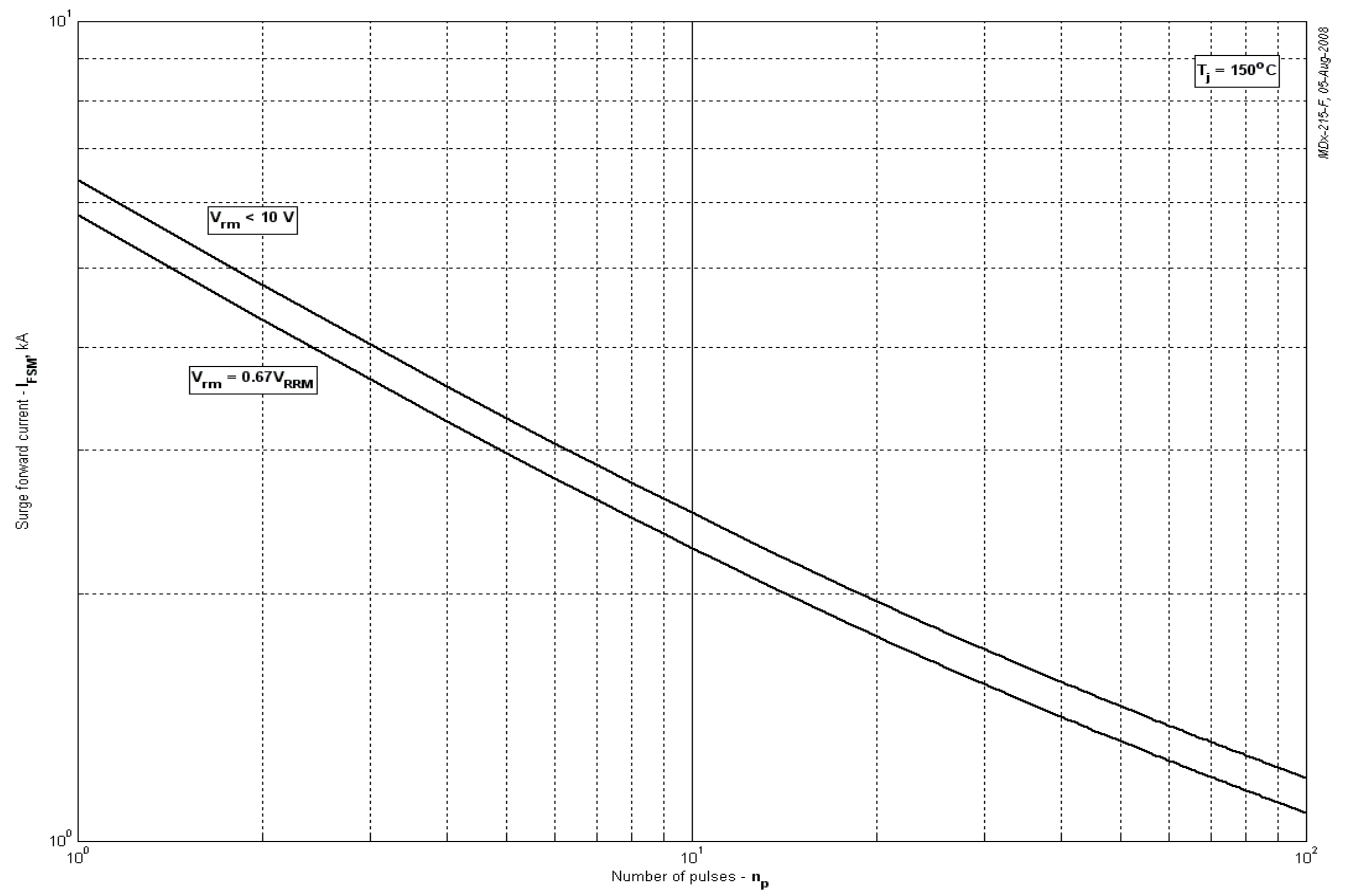


Fig 12 – Maximum surge ratings